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Huge laser-induced modulation of the ferromagnetic fraction in the antiferro-ferromagnetic mixed phase of FeRh

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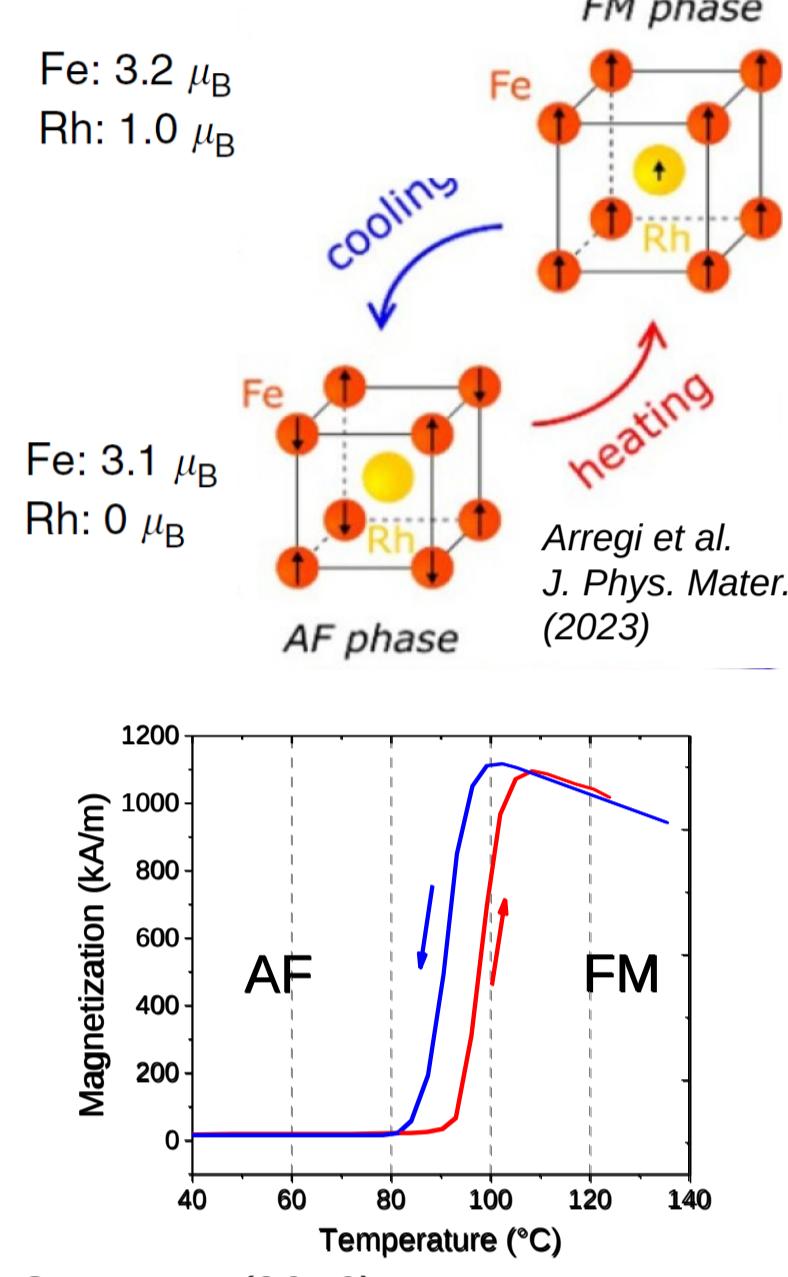
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Among magnetic materials near equi-atomic FeRh alloys, with their antiferromagnetic (AF) to ferromagnetic (FM) magneto-structural hysteretic transition near room temperature, were studied long ago in bulk form [Kouvel, JAP 1962, Lewis, J. Phys. D 2016]. In the recent years they have aroused a renewed interest as thin films with particular focus on the tuning of their AF-FM transition [Arregi, J. Phys. D: 2018, Ceballos, APL 2017], the electrical detection of their magnetic state with application to information coding [Marti, Nat. Mater., 2014], and their giant magneto-caloric effect [Nikitin, Phys. Lett. 1990, Manekar, J. Phys. D 2008].

FeRh is also a good candidate to investigate laser-assisted transient or irreversible first order phase transitions. Lattice expansion, nucleation of FM domains and magnetization dynamics have been studied using ultrafast pump-probe techniques. Here we show that low frequency (~ 100 kHz) modulated reflectance experiments provide an insight, not only on thermal effects (determination of the thermal conductivity) but also allows for a quantitative determination of the power dependent laser-induced FM fraction. Moreover we show that in the mixed AF-FM phase, the system exhibits return point memory under temperature cycling, i.e. it is capable of returning back to its initial state after a minor temperature loop, despite the hysteretic nature of the transition. Surprisingly, the same distribution of nucleation sites steering the transition in quasi-static conditions can explain the thermal hysteresis in far-from-equilibrium conditions when phase change is driven by sub- μ s temperature pulses.

1 FeRh: AF to FM transition

- Fe₅₀Rh₅₀: AF-FM transition close to room temperature
- isostructural transition but increase of the lattice parameter by 0.7 %
- change of the electronic structure
 - optical properties: 4% decrease of reflectivity from AF to FM
 - electrical properties: 40% drop of resistivity from AF to FM
- transition temperature tunable by
 - strain
 - magnetic field
- giant magnetocaloric effect
- information coding on two perpendicular AF states
- femtosecond laser-induced transient phase transition (Ju et al., PRL 2004, Bergman, PRB 2006, Radu PRB 2010, Mariager, PRL. 2012, Pressacco, Str. Dyn. 2018, Nat. Commun. 2021, Li, Nat. Com. 2022, Mattern Arxiv 2023)

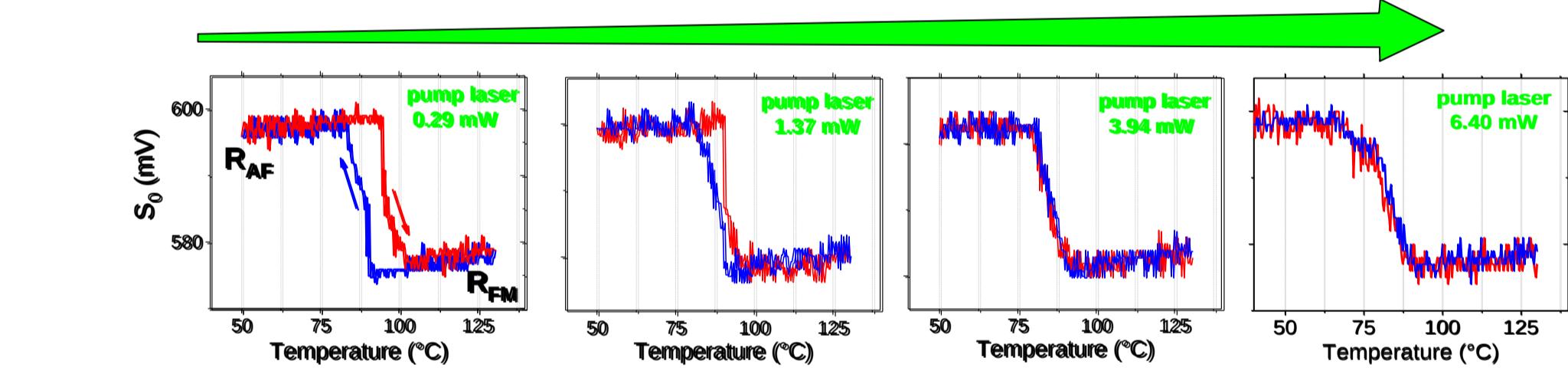


FeRh 200 nm
MgO (001) substrate

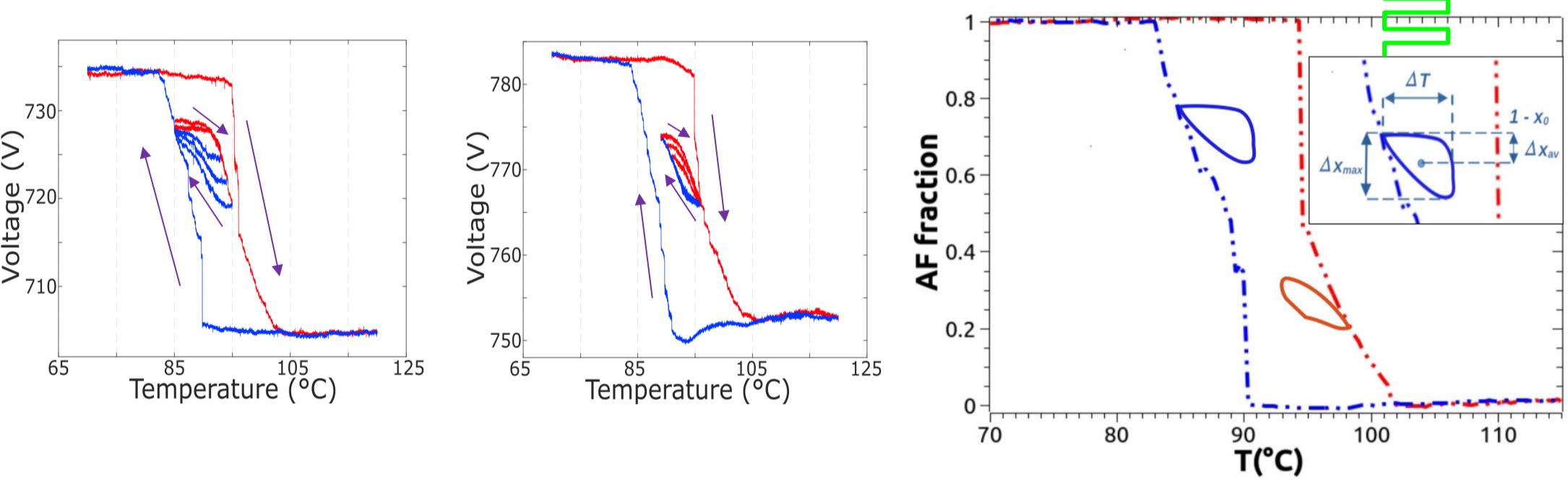
epitaxial FeRh films onto single-crystal MgO (001) substrates
post-growth annealing to obtain the CsCl-type (B2 ordering) crystal structure
cap layer Pt 2 nm

Sample growth at CEITEC by DC magnetron sputtering V. Uhlíř et al. Nat. Commun. (2016)

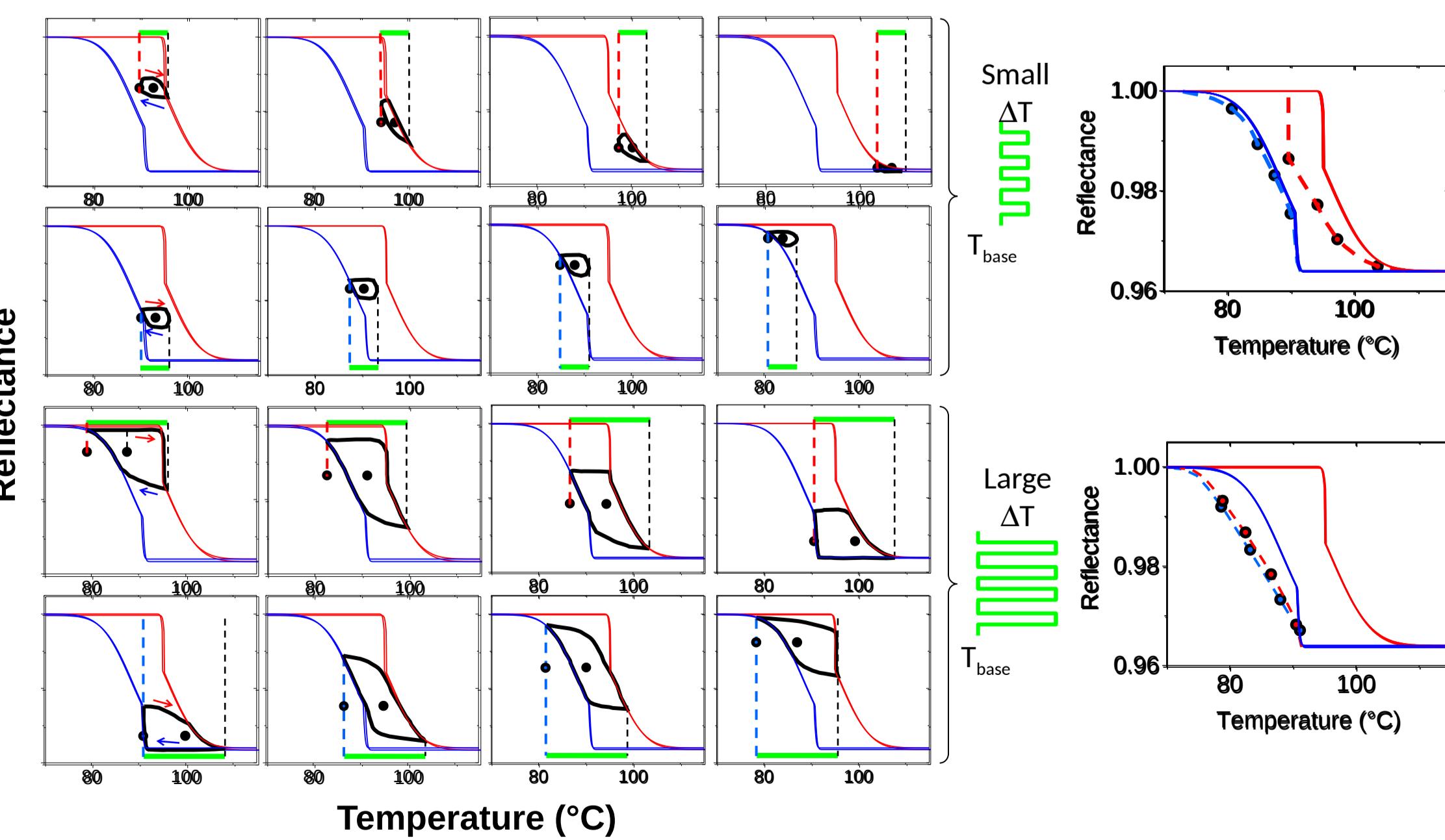
3 DC reflectance: apparent closing of the hysteresis cycle



Minor hysteresis loops: return point memory



The system exhibits **return-point memory (RPM)** a property wherein a system remembers the states at which the direction of an external driving (e.g. field, temperature...) had been reversed.

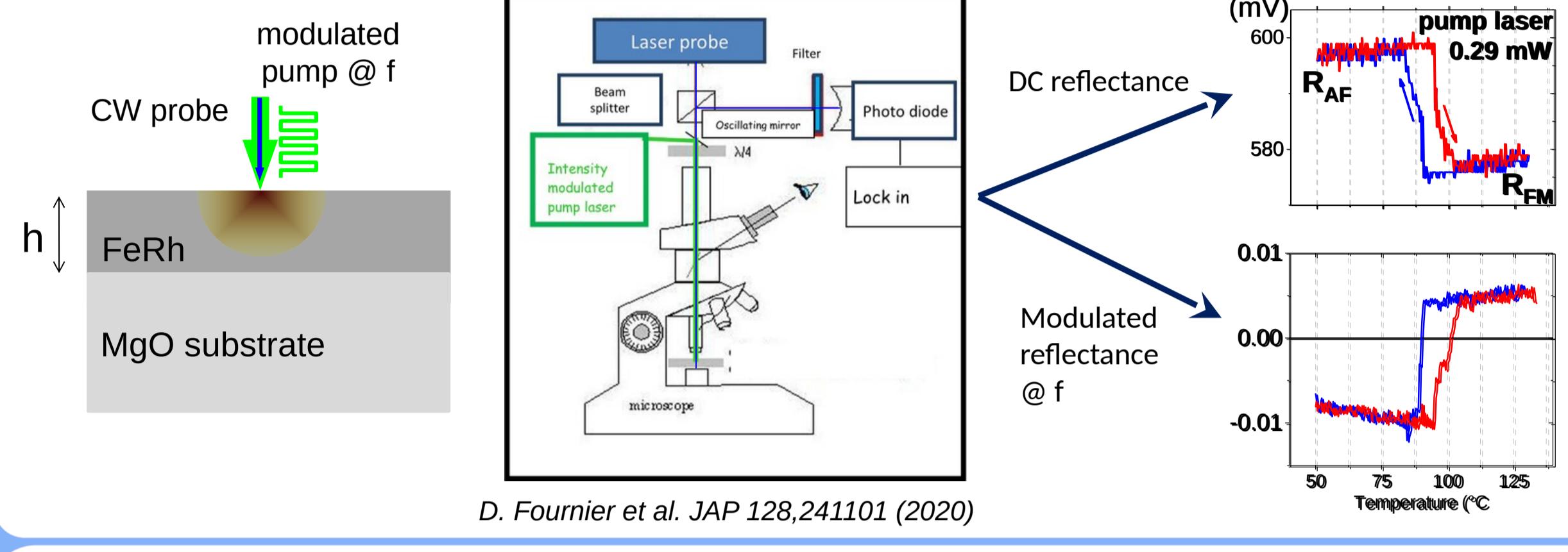


The DC signal hysteresis reduction under increasing pump power is a byproduct of plotting the DC signal as a function of T_{base}.

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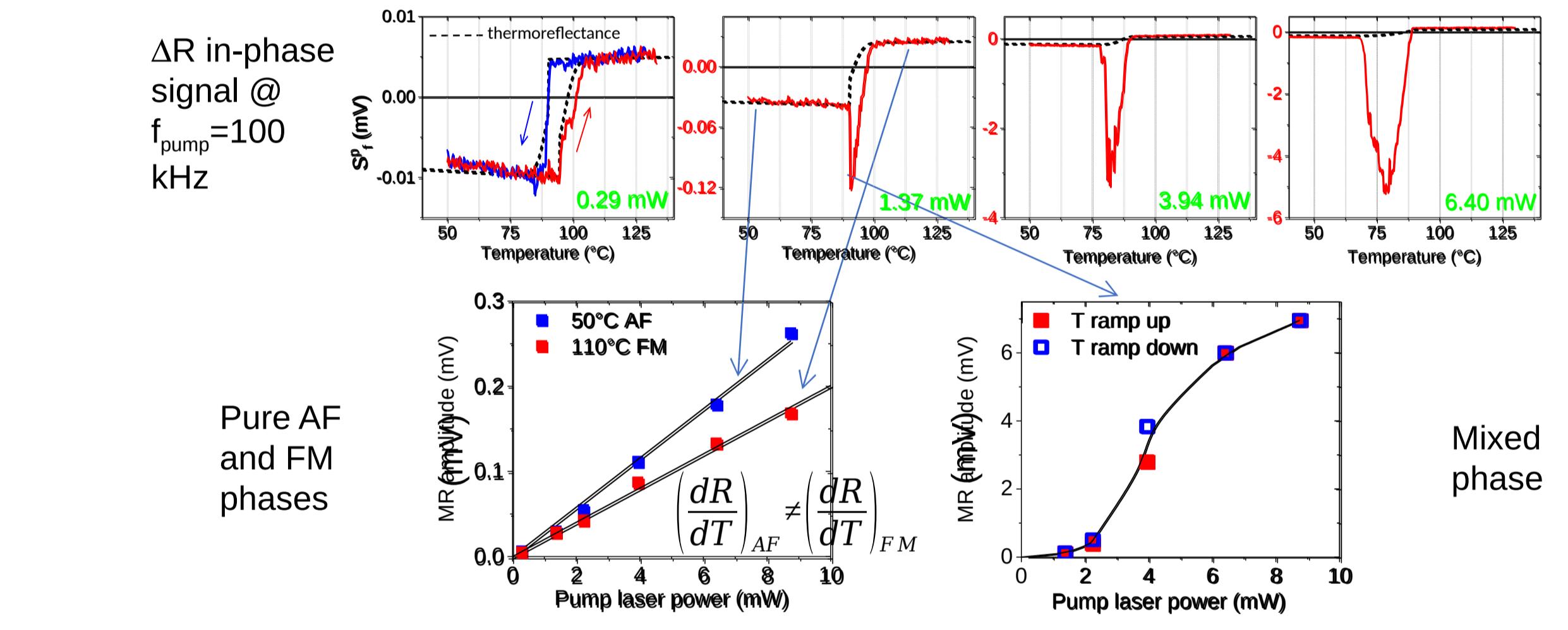
2 Modulated reflectance: experimental setup



4 Modulated reflectance: results

In AF and FM phase: only thermorelectance:

In the mixed AF-FM phase: a huge contribution from modulated FM fraction



(ΔT_{up} pump power) \propto linear pump-power dependence of ΔR in the pure AF and FM phases arising from thermorelectance

Non-linear pump-power dependence of ΔR in the mixed phase: contribution from the light-modulated FM Fraction

5 Quantitative determination of the modulated FM fraction

$$R = R_{AF}(1-x) + R_{FM}x$$

$$x(t) = x_0 + \Delta x(t)$$

non modulated FM fraction modulated FM fraction

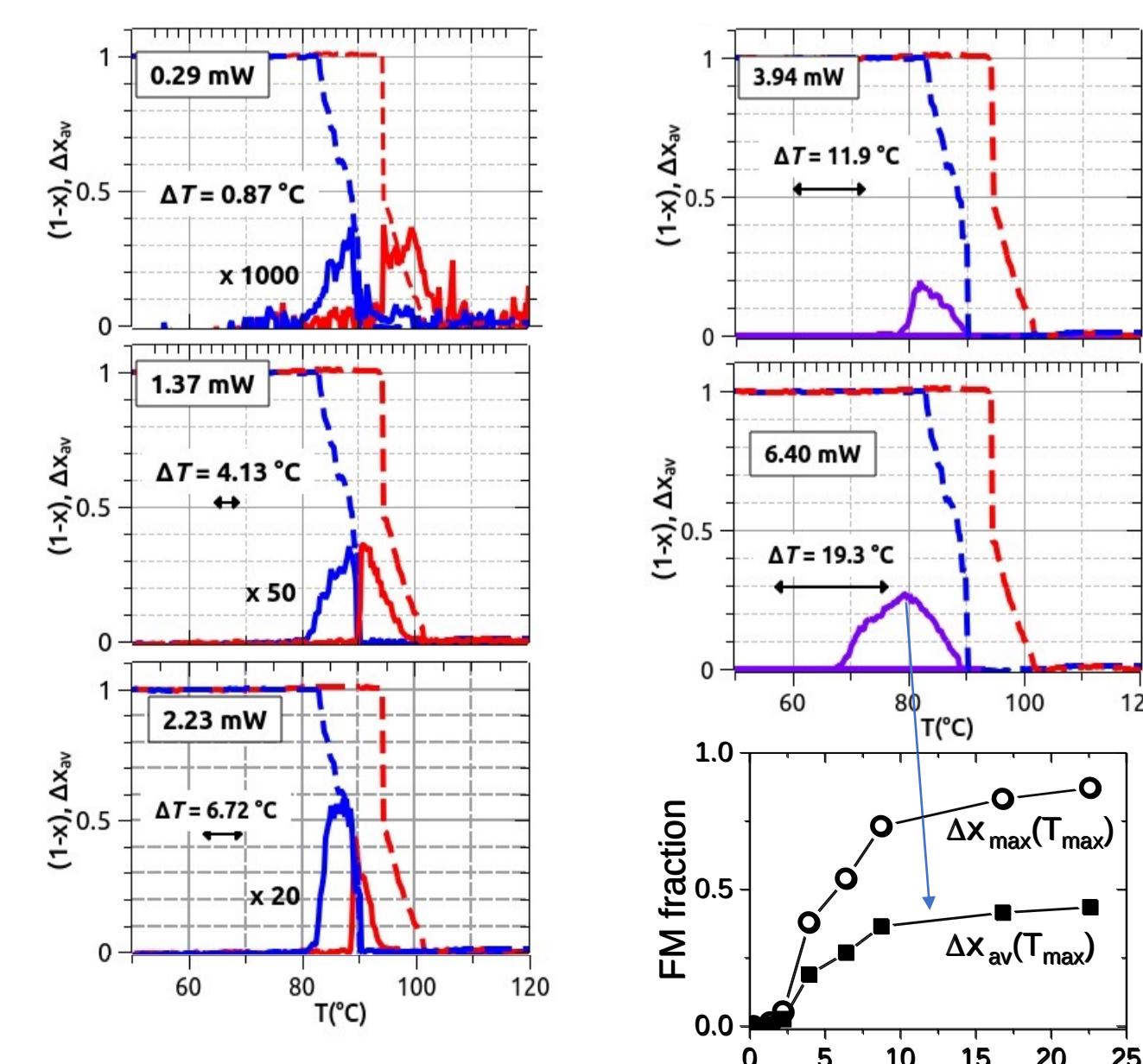
$$R = R(T_0) + \Delta R_{thermo} + \Delta R_x$$

$$\Delta R_x = \frac{dR}{dx} \Delta x = (-R_{AF} + R_{FM}) \Delta x$$

The modulated FM fraction becomes detectable owing to the large reflectivity difference between the AF and FM phases and is quantitatively determined using the modulated and DC reflectance

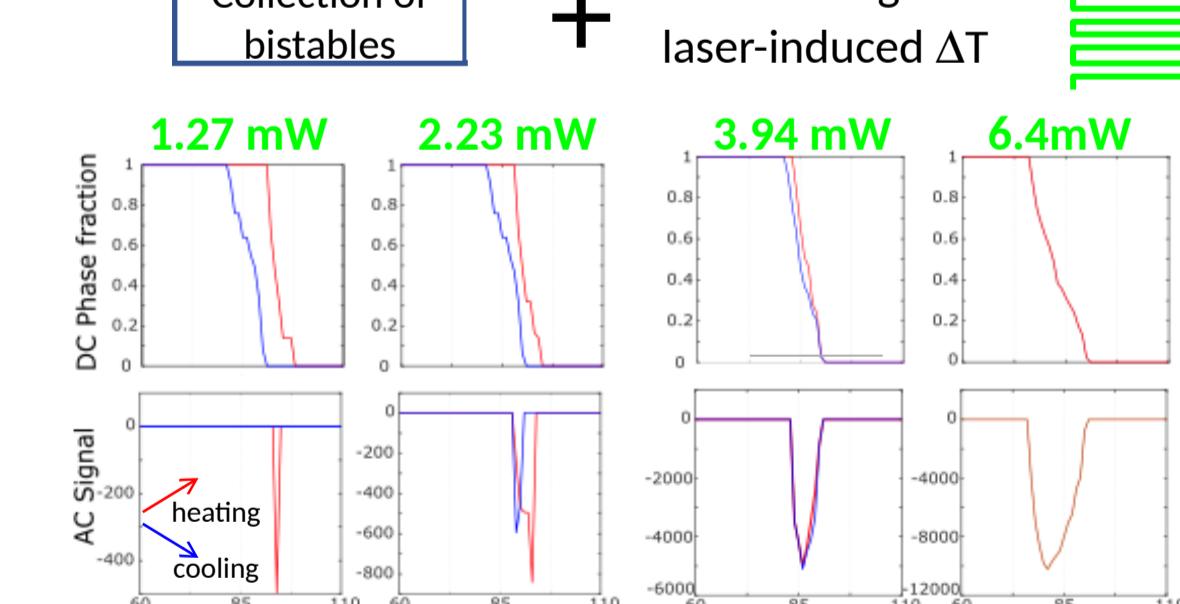
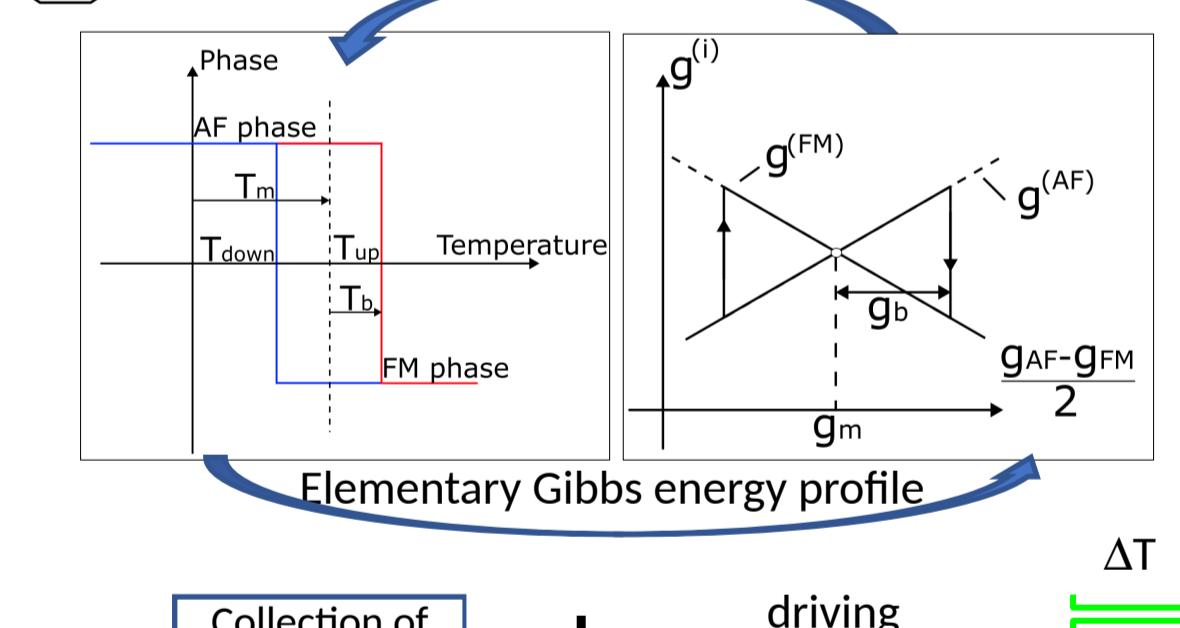
$$\Delta x_{av} = \frac{\pi \left(1 + \frac{S_f^{op}}{S_f^p} \right)^2}{2\sqrt{2}} \frac{R_{AF}}{-R_{AF} + R_{FM}} \frac{S_f^p}{S_0^{AF}}$$

in-phase reflectance signal out-of-phase reflectance signal DC reflectance signal in the AF phase



At high pump power, the light modulated FM fraction reaches 90% saturation

6 Hysteresis model



Quasi-static model can explain the apparent hysteresis closing
Under periodic driving he system reaches a stationary regime dominated by his rate-independent properties.

Model Explanation

- Bistable units factorization : $p(T_m, T_b) = a \exp\left(-\frac{\ln(T_b - \mu_b)^2}{2\sigma_b^2}\right) \exp\left(-\frac{T_m^2}{2\sigma_m^2}\right)$
- In magnetism, this factorization is generally associated with random distribution of nucleation centers

Temperature distribution

